

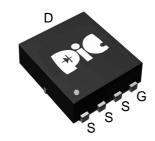
### General Description

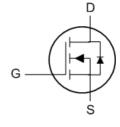
This PAN60SY48Y N-Channel enhancement mode power field effect transistor is the high density trench technology and this advanced technology can provide excellent Rds(On) performance and efficiency for power switching and load switching application., this device also comply with the RoHS and Green Product requirement with full function reliability approved.

### > Feature

- Super Low Gate Charge
- ●100% EAS Guaranteed
- •Green Device Available
- ●Excellent CdV/dt effect decline
- Advanced high cell density Trench technology

#### DFN5X6A-EP1





## > Application

- ●DC/DC Primary Side Switch
- Industrial Synchronous
- Rectification Load Switch
- ●DC/DC Converters

## > Absolute Maximum Ratings

Parameter	Symbol	Rating	Units
Drain-Source Voltage	Vos	60	V
Gate-Source Voltage	Vgs	±20	V
Continuous Drain Current <sub>1,6</sub>	Ip@Tc=25°C	85	А
Continuous Drain Current <sub>1,6</sub>	In@Tc=100°C	66	А
Pulsed Drain Current2	Ірм	240	А
Single Pulse Avalanche Energy <sub>3</sub>	EAS	101	mJ
Avalanche Current	las	45	А
Total Power Dissipation <sub>4</sub>	Pp@Tc=25°C	83	W
Storage Temperature Range	Тѕтс	-55 to 150	°C
Operating Junction Temperature Range	TJ	-55 to 150	°C
Thermal Resistance Junction-ambient 1	Reja	55	°CM
Thermal Resistance Junction-case 1	Reuc	1.5	°C/W



## Electrical Characteristics (T<sub>J</sub>=25°C Unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Drain-Source Breakdown Voltage	BVDSS	Vgs=0V , Ip=250uA	60			V	
Static Drain-Source On-Resistance <sub>2</sub>	RDS(ON)	Vgs=10V , ID=20A		3.0	3.6	mΩ	
	NDS(ON)	Vgs=4.5V , ID=15A		4.4	5.4	mΩ	
Gate Threshold Voltage	V <sub>GS(th)</sub>	Vgs=Vps, Ip =250uA	1.2		2.3	V	
Drain-Source Leakage Current	Ipss	VDS=48V , VGS=0V , TJ=25°C			1	1 uA	
	IDSS	VDS=48V , VGS=0V , TJ=55°C			5		
Gate-Source Leakage Current	Igss	Vgs=±20V , Vps=0V			±100	nA	
Forward Transconductance	gfs	Vps=5V , Ip=20A		65		S	
Gate Resistance	Rg	V <sub>DS</sub> =0V , V <sub>GS</sub> =0V , f=1MHz		0.7		Ω	
Total Gate Charge (10V)	Qg			58			
Gate-Source Charge	Qgs	VDS=30V , VGS=10V , ID=20A		16		nC	
Gate-Drain Charge	Qgd			4			
Turn-On Delay Time	T <sub>d(on)</sub>			18			
Rise Time	Tr	$V_{DD}$ =30 $V$ , $V_{GS}$ =10 $V$ , $R_{G}$ =3 $\Omega$ ,		8		no	
Turn-Off Delay Time	T <sub>d(off)</sub>	ID=20A		50		ns	
Fall Time	Tf			10.5			
Input Capacitance	Ciss			3458			
Output Capacitance	Coss	VDS=30V , VGS=0V , f=1MHz		1522		pF	
Reverse Transfer Capacitance	Crss			22			

## Diode Characteristics

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Continuous Source Current <sub>1,5</sub>	ls	V <sub>G</sub> =V <sub>D</sub> =0V , Force Current			55	Α
Diode Forward Voltage2	VsD	Vgs=0V , Is=1A , T <sub>J</sub> =25°C			1.2	V
Reverse Recovery Time	trr	IF=20A , dI/dt=100A/µs , TJ=25°C		24		nS
Reverse Recovery Charge	Qrr	717=20A, αί/αί=100A/μS, 13=25 C		85		nC

#### Note:

- 1. Pulse width limited by maximum junction temperature.
- 2.The data tested by pulsed , pulse width  $\leq$  300us , duty cycle  $\leq$  2%
- 3. The EAS data shows Max. rating . The test condition is  $V_{DD}$ =50V,  $V_{GS}$ =10V, L=0.1mH,  $I_{AS}$ =45A
- 4.Ensure that the channel temperature does not exceed 150°C.
- 5.The data is theoretically the same as ID and IDM, in real applications, should be limited by total power dissipation.
- 6. The maximum current rating is package limited.



## > Typical Characteristics

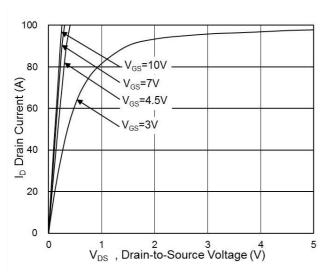


Fig.1 Typical Output Characteristics

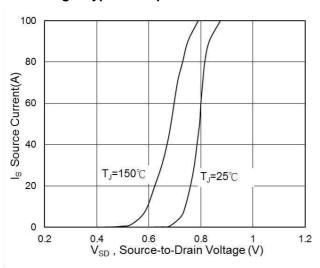


Fig.3 Diode Forward Voltage vs. Current

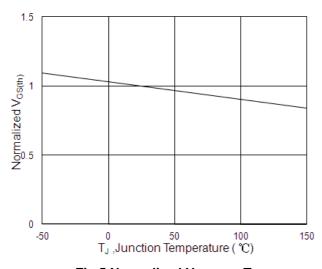


Fig.5 Normalized V<sub>GS(th)</sub> vs T<sub>J</sub>

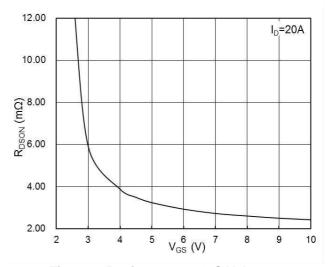


Fig.2 On-Resistance vs G-S Voltage

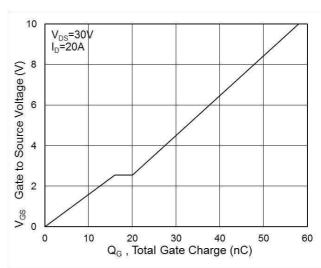


Fig.4 Gate-Charge Characteristics

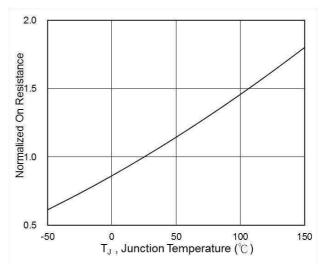
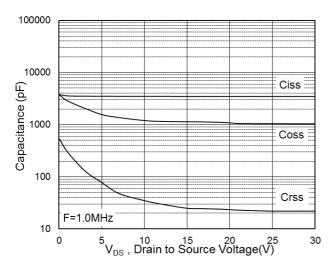


Fig.6 Normalized R<sub>DSON</sub> vs T<sub>J</sub>





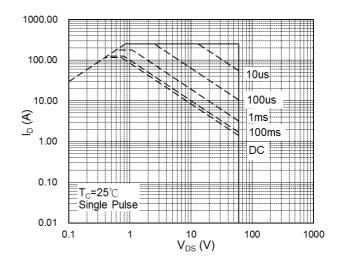


Fig.7 Capacitance

Fig.8 Safe Operating Area

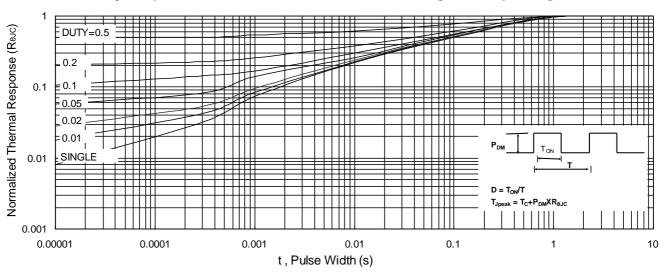


Fig.9 Normalized Maximum Transient Thermal Impedance

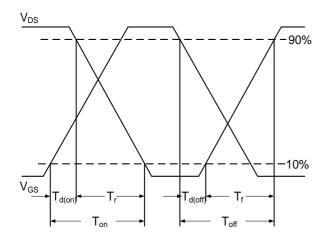


Fig.10 Switching Time Waveform

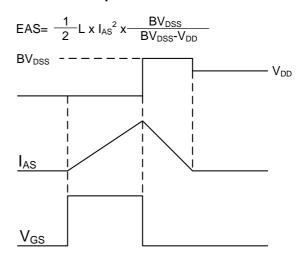
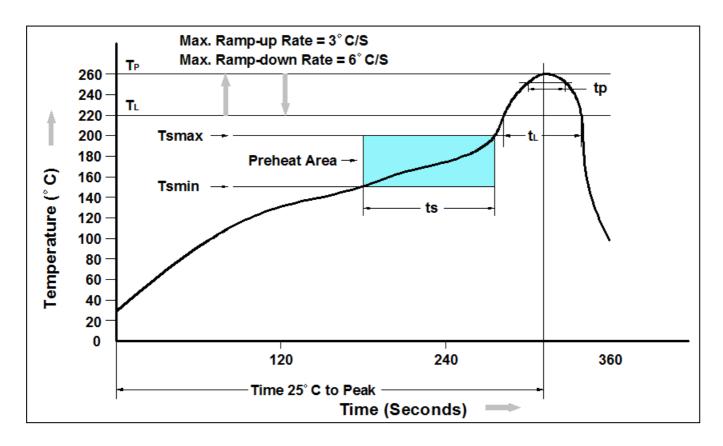


Fig.11 Unclamped Inductive Switching Waveform



## Recommand IR Reflow Soldering Thermal Profile



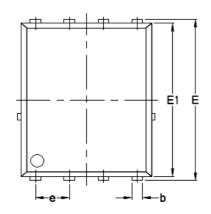
Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Average Ramp-up Rate (tL to tP)	3°C/second max.
Liquidous Temperature (TL)	217°C
Time (tL) Maintained Above (TL)	60 – 150 seconds
Peak Temperature	260°C +0°C / -5°C
Time (tP) within 5°C of actual Peak Temperature	30 seconds
Ramp-down Rate (TP to TL)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.

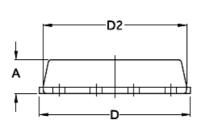
## Ordering Information

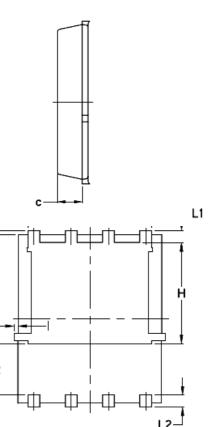
Part Number	Description	Quantity
PAN60SY48Y	DFN5X6A-EP1 Reel	3000 pcs



## Package Information ( DFN5X6A-EP1 )







SYMBOLS	MILLIM	METERS	INCHES		
STIVIBULS	MIN	MAX	MIN	MAX	
А	1.03	1.17	0.0406	0.0461	
b	0.34	0.48	0.0134	0.0189	
С	0.824	0.970	0.0324	0.0382	
D	4.80	5.40	0.1890	0.2126	
D1	4.11	4.31	0.1618	0.1697	
D2	4.80	5.00	0.1890	0.1969	
I		0.18		0.0070	
Е	5.90	6.15	0.2323	0.2421	
E1	5.65	5.85	0.2224	0.2303	
E2	1.10		0.0433		
е	1.27 BSC		0.05	BSC	
Н	3.30	3.78	0.1299	0.1488	
L	0.05	0.25	0.0020	0.0098	
L1	0.38	0.61	0.0150	0.0240	
L2	0.38	0.71	0.0150	0.0279	





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